October 2005 V2

GaAs DC-3 GHz SPDT Terminated Switch



Features

- Low Insertion Loss: 0.40 dB @ 0.87 GHz
 0.50 dB @ 2.5 GHz
- High Isolation: 55 dB @ 0.87 GHz

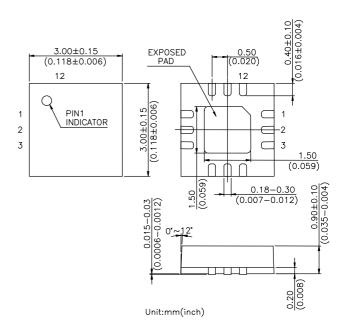
47 dB @ 2.5 GHz

- 50 or 75 Ohm Systems
- Low DC Power Consumption
- Miniature QFN12L (3x3 mm) Plastic Lead (Pb) Free Package
- RoHS (Restrict of Hazardous Substances)
 Compliant

Description

The HWS429 is a GaAs SPDT terminated (non-reflective) switch operating at DC-3 GHz in a low cost QFN12L (3x3 mm) plastic lead (Pb) free package. The HWS429 features low insertion loss and high isolation with very low DC power consumption and can be used in both 50 ohm and 75 ohm systems. Typical applications include CATV and basestation systems for either SPDT or SPST functions.

QFN12L (3 x 3 mm)



Electrical Specifications at 25 °C with 0, +3V Control Voltages, 50 Ohm system

| Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|--|---------------------------|------|------------|------|----------|
| Insertion Loss | DC-1.5 GHz 1.5-3.0 GHz | | 0.4 0.5 | 0.8 | dB dB |
| Isolation | DC-1.5 GHz 1.5-3.0 GHz | 35 | 53 43 | | dB dB |
| Return Loss | DC-3.0 GHz | | 15 | | dB |
| Input Power for One dB Compression | 0.5-3.0 GHz | | 26 | | dBm |
| Input Third Order Intermodulation Intercept Point | 0.5-3.0 GHz | | 45 | | dBm |
| Switching Time | | | 50 | | ns |
| Control Current | | | 30 | 300 | uA |

Note: All measurements made in a 50 ohm system with related application circuits and 0/+3V control voltages, unless otherwise specified.

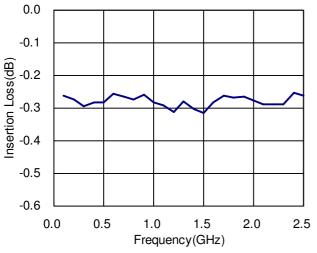


GaAs DC-3 GHz SPDT Terminated Switch

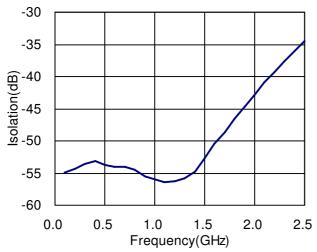
October 2005 V2

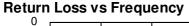
Typical Performance Data With Application Circuit A @ +25 ℃

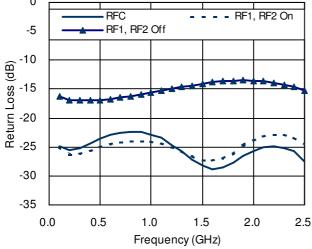
Insertion Loss vs Frequency



Isolation vs Frequency

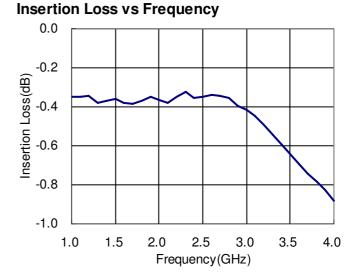




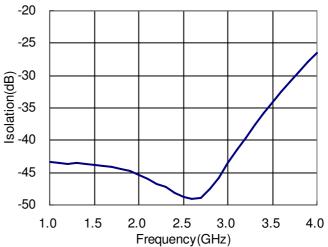


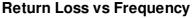
Application Circuit B @ +25 ℃

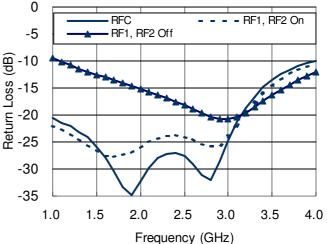
Typical Performance Data With



Isolation vs Frequency







Hexawave Inc. 1F, 2 Prosperity Road II, Science Park, Hsinchu, Taiwan. TEL 886-3-578-5100 FAX 886-3-577-0512
http://www.hw.com.tw

All specifications are subject to change without notice.

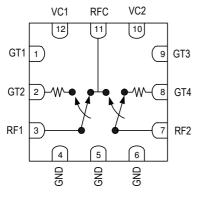


October 2005 V2

Absolute Maximum Ratings

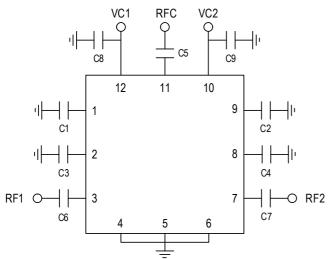
| Parameter | Absolute Maximum | | |
|-----------------------|------------------|--|--|
| RF Input Power | +32 dBm @ +5V | | |
| Control Voltage | +6V | | |
| Operating Temperature | -40 ℃ to +85 ℃ | | |
| Storage Temperature | -65℃ to +150℃ | | |

Pin Out (Top View)



Exposed pad in the bottom must be connected to ground by via holes.

Application Circuits



Component Values:

| Circuit | C1, C2 | C3, C4 | C5, C6, C7 | C8, C9 |
|---------|--------|--------|------------|--------|
| А | 47pF | 330pF | 1000pF | 47pF |
| В | 2pF | 4pF | 47pF | 47pF |

Note: Circuit A and B are optimized for DC-1.5 GHz and 1.5-3.0 GHz, respectively.

Logic Table for Switch On-Path

| VC1 | VC2 | RFC-RF1 | RFC-RF2 |
|-----|-----|----------------|----------------|
| 0 | 1 | Insertion Loss | Isolation |
| 1 | 0 | Isolation | Insertion Loss |

'1' = +3V to +5V '0' = 0V to +0.2V